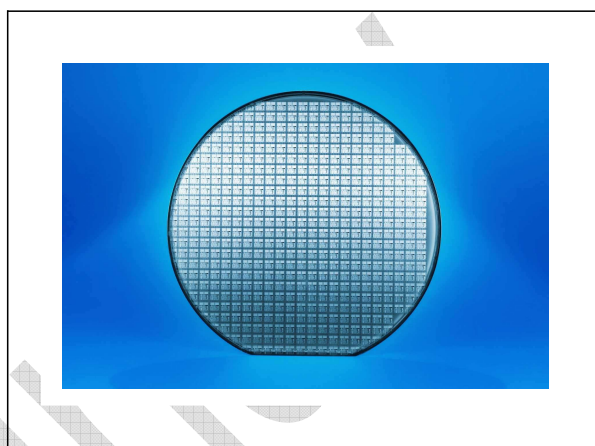


## Power Management Unit

### Features

- 3 low quiescent current LDO
- 5V input, 1.6V output buck converter
- Extra low operating current voltage source output
- Programmable current source, 150mA max.
- Serial Bus control
- Over current protection on LDO
- Switch between adaptor and battery as power supply
- Ship in wafer form



### Description

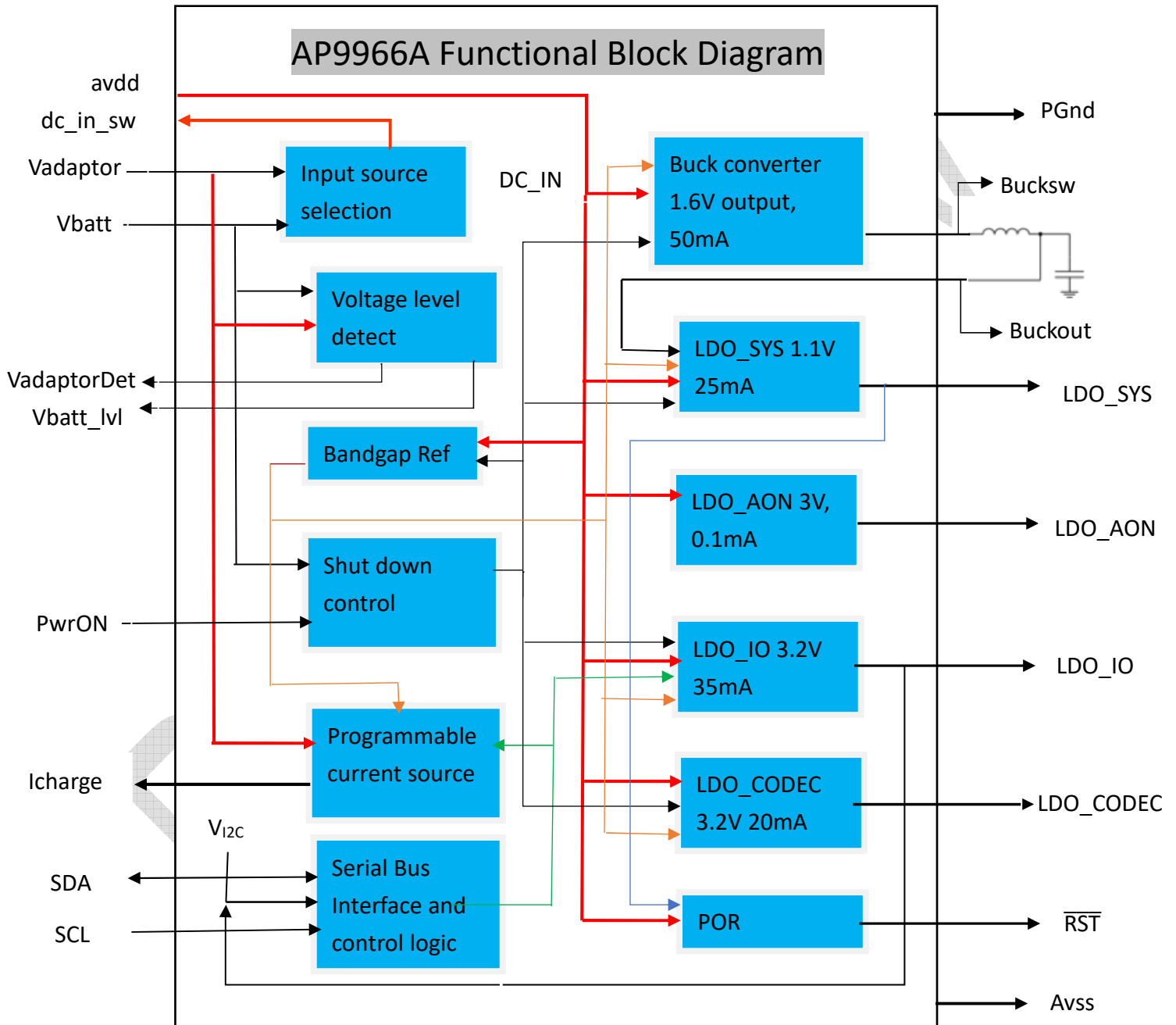
The AP9966A is a power management unit containing high efficiency bulk converter (DC-DC step down) and low quiescent current Low Drop Out (LDO) regulators. A programmable current source output to be used in conjunction with external MCU will enable Lithium battery charging with no external component.

Outputs of selected LDOs are protected from short-circuit by limiting current to be delivered.

Output voltages of specific LDOs and current source can be altered through serial bus connected between the chip and the external MCU.

Units will be shipped in 8" wafer form.

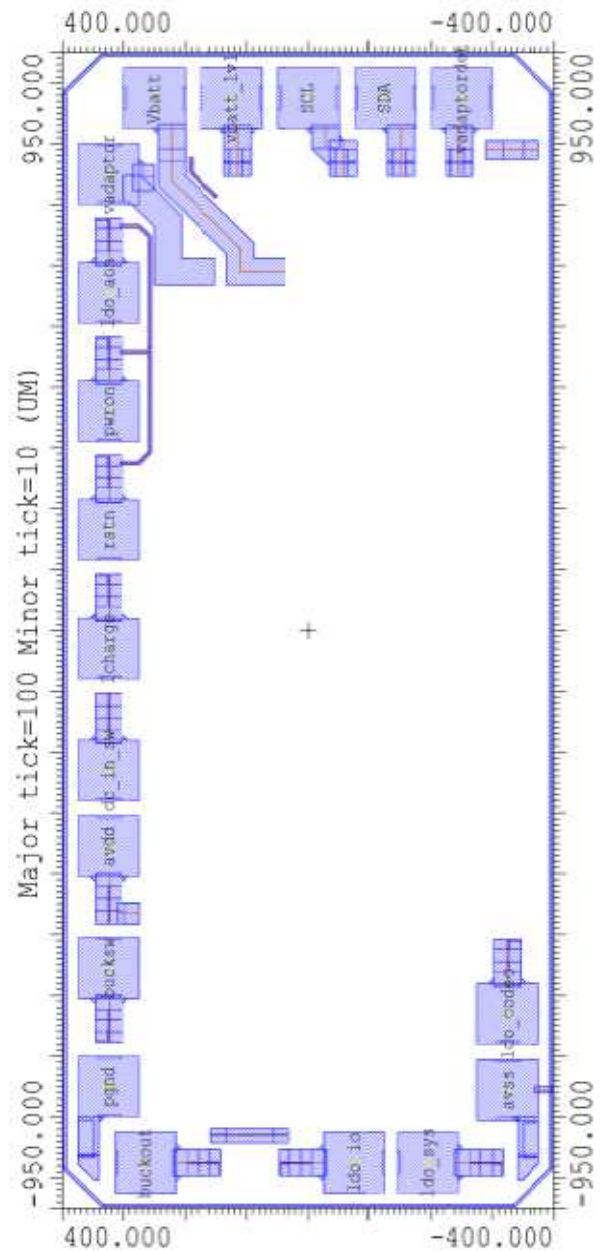
# 1 Device block diagram



## 2 Pin description

### 2.1 Pin out

There are 19 bonding pads on the chip. See below for the pad assignment.



### 3 Electrical specifications

#### 3.1 Absolute maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
VDD	DC supply voltage	5.75	V
T <sub>op</sub>	Operating temperature	0 to 85	°C
T <sub>j</sub>	Junction temperature	-40 to 150	°C
T <sub>sto</sub>	Storage temperature	-40 to 150	°C
HBM	ESD Susceptibility	2000	V
MM	ESD Susceptibility	200	V

#### 3.2 Thermal data

Table 4. Thermal data

Symbol	Parameter	Min	Typ	Max	Unit
			N/A		°C/W

#### 3.3 Electrical specifications

Unless otherwise stated, the results in [Table 5](#) below are given for the conditions: Vadaptor = 5V, and T<sub>A</sub> = 25 °C.

Table 5. Electrical specifications

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>POWER SUPPLY</b>						
V <sub>daptor</sub>	Supply voltage for pin V <sub>daptor</sub>		4.75	5	5.5	V
I <sub>cc</sub>	Total quiescent current	No load, all devices turned on		900		µA
I <sub>shutdown</sub>	Shut down current	PwrON=0; Reg <sub>01</sub> =0x00, No adaptor power		4		µA
<b>BUCK CONVERTER</b>						
V <sub>Buck6</sub>	1.5V buck converter output	No load	1.47	1.6	1.73	V
	1.5V buck line regulation	No load V <sub>dc_in</sub> =5.5V to 3V		15	20	mV
	1.5V buck load regulation	I <sub>load</sub> =1mA to 50mA V <sub>dc_in</sub> =5V		15		mV
f <sub>Buck</sub>	Buck converter operating frequency	Temperature range 0°C to 85°C	0.8	1	1.35	MHz
V <sub>ripple</sub>	Peak to peak ripple voltage	I <sub>load</sub> =50mA		25		mV
η	Efficiency	I <sub>load</sub> =5mA		83		%

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>LDO_SYS</b>						
V <sub>LDO_SYS</sub>	1.1V regulator output	No load	1.02	1.1	1.18	V
	line regulation	No load V <sub>dc</sub> =5.5V to 3.3V		14		mV
	load regulation	I <sub>load</sub> = 1mA to 25mA		33		mV
PSRR <sub>Ldo</sub>	Supply rejection	AC input 0.1V pk-pk at V <sub>dc</sub> ; V <sub>dc</sub> =5V DC f=1kHz f=DC		45 60		dB
I <sub>gnd</sub>	Ground current without load	No Load		10*		μA
V <sub>drop-out</sub>	Drop out voltage (V <sub>in</sub> – V <sub>out</sub> )	I <sub>load</sub> = 25mA		200		mV
<b>LDO_IO</b>						
V <sub>LDO_IO</sub>	3.2V regulator output	No load	2.94	3.2	3.46	V
	line regulation	No load V <sub>dc</sub> =5.5V to 3.35V		30	50	mV
	load regulation	I <sub>load</sub> = 1mA to 35mA		30		mV
PSRR <sub>Ldo</sub>	Supply rejection	AC input 0.1V pk-pk at V <sub>dc</sub> ; V <sub>dc</sub> =5V DC f=1kHz f=DC		45 60		dB
I <sub>gnd</sub>	Ground current without load	No Load		10*		μA
V <sub>drop-out</sub>	Drop out voltage (V <sub>in</sub> – V <sub>out</sub> )	I <sub>load</sub> = 35mA, V <sub>LDO_IO</sub> =3.2V		200		mV
<b>LDO_CODEC</b>						
V <sub>LDO_CODEC</sub>	3.2V regulator output	No load	2.94	3.2	3.46	V
	line regulation	No load V <sub>dc</sub> =5.5V to 3.35V		30	50	mV
	load regulation	I <sub>load</sub> = 1mA to 20mA		30		mV
PSRR <sub>Ldo</sub>	Supply rejection	AC input 0.1V pk-pk at V <sub>dc</sub> ; V <sub>dc</sub> =5V DC f=1kHz f=DC		45 60		dB
I <sub>gnd</sub>	Ground current without load	No Load		10*		μA
V <sub>drop-out</sub>	Drop out voltage (V <sub>in</sub> – V <sub>out</sub> )	I <sub>load</sub> = 20mA, V <sub>LDO_CODEC</sub> =3.2V		200		mV
<b>LDO_AON</b>						
V <sub>LDO_AON</sub>	Low power regulator output			3		V
I <sub>LDO_OUT</sub>	Maximum output current			100		μA
I <sub>q_LDO_AON</sub>	Quiescent operating current	No load		4		μA

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>SERIAL INTERFACE (SDA, SCL I/O Characteristics; Pull-up resistors on SDA and SCL is 4.7kohm)</b>						
V <sub>I2C</sub>	I <sup>2</sup> C power supply	V <sub>I2C</sub> = V <sub>LDO_IO</sub>	2.94	3.2	3.46	V
V <sub>IH</sub>	High input level; SCL, SDA		0.7V <sub>I2C</sub>			V
V <sub>IL</sub>	Low input level; SCL, SDA				0.3V <sub>I2C</sub>	V
V <sub>OL</sub>	Low output level, SDA	Sink current=3mA			0.4	V
I <sub>2C</sub> clock	Maximum clock on SCL	Internal pull up only			100	KHz
<b>Charging current</b>						
V <sub>daptor</sub>	Operating voltage		4.75		5.5	V
I <sub>charge</sub>	Output current	Reg <sub>01</sub> =0x07		150		mA
I <sub>charge</sub>	Output current	Reg <sub>01</sub> =0x00		0		mA
	Refer to table 7 of Section 4 for register bit assignment					
I <sub>OFF</sub>	RSTn	Output leakage current, tied to 3V			1	μA
V <sub>OL</sub>	RSTn	I <sub>out</sub> = -500μA; current going into the pin	0.2			V
TSD	Thermal Shut Down	Active mode, 15degC hysteresis		150		degC
<b>Power condition signals</b>						
V <sub>daptor_Det</sub>	Logic signal to MCU	% of V <sub>daptor</sub>		50		%
V <sub>batt_lvl</sub>	Analog signal to MCU	% of V <sub>Batt</sub> , output = 3V when battery voltage is 4.2V		70		%

\* data obtained from design simulation, cannot be measured at chip or wafer level. The current consumption will be reflected on the quiescent operating current.